650V 4A N-Channel Enhancement Mode Power MOSFET

General Description

BXP4N65 is Bridgelux high voltage MOSFET family based on advanced planar stripe DMOS technology. This advanced MOSFET family has optimized on-state resistance, and also provides superior switching performance and higher avalanche energy strength. This device family is suitable for high efficiency switch mode power supplies.

FEATURES

- RDSON≤2.8 Ω @Vgs=10V, Id=2A
- Excellent RDS(ON) and Low Gate Charge
- Fast switching capability
- Lead free product is acquired

SYMBOL





TO-251L



TO-252

TO-220F

ASSEMBLY MESSAGE

Product Name	Marking	Package	Packaging
BXP4N65U	BXP4N65U	TO-251L	Tube
BXP4N65D	BXP4N65D	TO-252	Tube/Reel
BXP4N65P	BXP4N65P	TO-220	Tube
BXP4N65F	BXP4N65F	TO-220F	Tube

TO-220

ABSOLUTE MAXIMUM RATINGS (T_C=25°C unless otherwise noted)

Parameter		Symbol	Rating			Unit
		Symbol	BXP4N65U/D	BXP4N65P	BXP4N65F	Unit
Drain-Source Voltage		V _{DSS}	650			V
Continuous ($T_c = 25^{\circ}C$)			4			А
Drain Current	Continuous (T _c = 100°C)		2.5			А
Drain Current	Pulsed (Note1)	I _{DM}	16			А
Gate-Source Voltage		V _{GSS}	±30			V
	Single Pulse (Note2)	E _{AS}	220			mJ
Avalanche Energy	Repetitive (Note1)	E _{AR}	15			mJ
Avalanche Current (Note1)		I _{AR}	4			А
Peak Diode Recovery dv/dt (Note3)		dv/dt	5			V/ns
Power Dissipation (Note	T _C =25°C	- Po	77	98	37	W
2)	Derate above 25°C		0.62	0.79	0.3	W/°C
Maximum Junction Temperature		TJ	150			°C
Storage Temperature Range		T _{STG}	-55 to 150			°C

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

2. L=27.5mH, I_{AS}=4.0A, V_{DD}=50V, RG=25 $\Omega,$ Starting TJ = 25°C

3. I_{SD} \leq 4.0A, di/dt \leq 300A/µs, V_{DD} \leq BV_{DSS}, Starting TJ = 25°C



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THERMAL CHARACTERISTICS

Deremeter	Symbol		Unit		
Parameter	Symbol	BXP4N65U/D	BXP4N65P	BXP4N65F	Unit
Thermal Resistance, Junction-to-Case	R _{θJC}	1.62	1.27	3.35	°C / W
Thermal Resistance, Junction-to-Ambient R ₀ ,		110	62	120	°C / W

ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise Noted)

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS	I			1		1
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V, ID=250µA	650			V
		VDS=650V, VGS=0V			1	uA
Zero Gate Voltage Drain Current	I _{DSS}	VDS=520V, TC = 125°C			100	uA
Gate-Body Leakage Current, Forward		VGS=30V			100	nA
Gate-Body Leakage Current, Reverse	- I _{GSS}	VGS=-30V			-100	nA
Breakdown Voltage Temperature	∆BVDSS/			0.00		
Coefficient	∆TJ	ID = 250 μA		0.62		V/℃
ON CHARACTERISTICS			•			
Gate Threshold Voltage	V _{GS(TH)}	VDS=VGS, ID=250µA	2		4	V
Drain-Source On-State Resistance	RDS(ON)	VGS=10V, ID=2A		2.4	2.8	Ω
Forward Transconductance (Note4)	g fs	VDS = 50V, ID = 2A		2.5		S
DYNAMIC PARAMETERS						
Input Capacitance	C _{ISS}			545		pF
Output Capacitance	Coss	VDS=25V, VGS=0V,		54		pF
Reverse Transfer Capacitance	Crss	f=1.0MHz		5		pF
SWITCHING PARAMETERS				·	·	
Turn-ON Delay Time	t _{D(ON)}			11		ns
Turn-ON Rise Time	t _R	VDD=325V, ID=4 A, VGS =		25		ns
Turn-OFF Delay Time	t _{D(OFF)}	10V ,RG=10Ω		32.5		ns
Turn-OFF Fall-Time	t⊨	(Note4,5)		7		ns
Total Gate Charge(Note5)	Q _G	VDS =520V, VGS =10V, ID		13		nC
Gate Source Charge	Q _{GS}	=4A		3.4		nC
Gate Drain Charge	Q _{GD}	(Note4,5)		7		nC
SOURCE- DRAIN DIODE RATINGS	AND CHARA	ACTERISTICS				
Drain-Source Diode Forward Voltage	V _{SD}	IS=4A, VGS=0V			1.4	V
Diode Continuous Forward Current	Is				4	Α
Pulsed Drain-Source Current	I _{SM}				16	Α
Reverse Recovery Time	t _{RR}	VGS = 0 V, ISD = 4A		510		ns
Reverse Recovery Charge	Q _{RR}	di/dt=100 A/µs (Note4,5)		2.5		uC

Note: 4. Pulse Test : Pulse width \leq 300µs, Duty cycle \leq 2%

5. Essentially independent of operating temperature



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TYPICAL CHARACTERISTICS





TYPICAL CHARACTERISTICS(Cont.)



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TEST CIRCUITS AND WAVEFORMS



Gate Charge Test Circuit



Gate Charge Waveform



Resistive Switching Test Circuit

Resistive Switching Waveforms

TEST CIRCUITS AND WAVEFORMS(Cont.)



Diode Reverse Recovery Test Circuit

Diode Reverse Recovery Waveform



Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms



BXP4N65

Revision history

Document revision history

Date	Revision	Changes
15-Oct-2020	1.0	First release
10-Nov-2021	1.1	Update layout format
4-Jan-2022	1.2	Update parameter

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